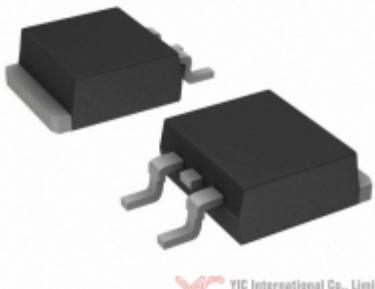

	<h2 style="color: red;">FQB6N60CTM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB6N60CTM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 600V 5.5A D2PAK
	Datenblätter:  FQB6N60CTM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 4940 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB6N60CTM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 600V 5.5A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	4940 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	5.5A (Tc)
Rds On (Max) @ Id, Vgs	2 Ohm @ 2.75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	810pF @ 25V
Verpackung	Tape & Reel (TR)


















































FQB6N60CTM ist neu im Original. Suche FQB6N60CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB6N60CTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB6N60CTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB6N70 FSC FQB6N70 FSC</p>	 <p>FQB6N60 FSC FQB6N60 FSC</p>	 <p>FQB6N60C Fairchild/ON Semiconductor FQB6N60C FAIRCHILD</p>	 <p>FQB6N60TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 6.2A D2PAK</p>
 <p>FQB6N60TM Fairchild/ON Semiconductor MOSFET N-CH 600V 6.2A D2PAK</p>	 <p>FQB6N50TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 5.5A D2PAK</p>	 <p>FQB6N60CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 5.5A D2PAK</p>	 <p>FQB6N70TM Fairchild/ON Semiconductor MOSFET N-CH 700V 6.2A D2PAK</p>

heiße Teile

Mehr

 FQB5N20L	 FQB5N30TM	 FQB5N30TM	 FQB5N50C	 FQB5N50CF
 FQB5N50CTM	 FQB5N50CTM	 FQB5N60CTM	 FQB5N60CTM	 FQB5N90TM
 FQB5N90TM	 FQB5P10TM	 FQB5P10TM	 FQB630TM	 FQB630TM
 FQB65N06	 FQB65N06TM	 FQB65N06TM	 FQB6N40C	 FQB6N40CF
 FQB6N40CTM	 FQB6N40CTM	 FQB6N50TM	 FQB6N50TM	 FQB6N60C
 FQB6N60CTM	 FQB6N60TM	 FQB6N60TM	 FQB6N70TM	 FQB6N70TM
 FQB6N90TM	 FQB6N90TM_AM002	 FQB6N90TM_AM002	 FQB7042FB	 FQB7045FB
 FQB70N03	 FQB70N06	 FQB70N08	 FQB70N10TM	 FQB7N10L
 FQB7N20L	 FQB7N60TM	 FQB7N60TM	 FQB7N65C	 FQB7N65CTM
 FQB7N65CTM	 FQB7P20TM	 FQB7P20TM	 FQB85N06	 FQB85N06TM

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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